

| Micron DigiKey® (接上页)   |               |            |            | 闪存 - 符合 RoHS 规范要求 |       |       |       |
|-------------------------|---------------|------------|------------|-------------------|-------|-------|-------|
| Micron Technology 零件编号  | Digi-Key 零件编号 | 描述         |            | 封装                | 单价★   |       |       |
| MT29F2G16AADWP-D TR     | 557-1358-2-ND | 2Gb, 3.3V  | 2Gb, 3.3V  | 48-TSOP           | 1     | 10    | 25    |
| MT29F2G16AADWP-ET-D TR  | 557-1359-1-ND | 2Gb, 3.3V  | 2Gb, 3.3V  | 48-TSOP           | 11.64 | 10.63 | 9.87  |
| MT29F2G16AADWP-ET-D TR  | 557-1359-2-ND | 2Gb, 3.3V  | 2Gb, 3.3V  | 48-TSOP           | 11.64 | 10.63 | 9.87  |
| MT29F2G16ABDHC-D TR     | 557-1360-1-ND | 2Gb, 1.8V  | 2Gb, 1.8V  | 63-VFBGA          | 12.30 | 11.14 | 10.21 |
| MT29F2G16ABDHC-ET-D TR  | 557-1361-1-ND | 2Gb, 1.8V  | 2Gb, 1.8V  | 63-VFBGA          | 11.64 | 10.63 | 9.87  |
| MT29F4G08AACWC-C TR     | 557-1362-1-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 11.60 | 10.60 | 9.84  |
| MT29F4G08AACWC-C TR     | 557-1362-2-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 11.60 | 10.60 | 9.84  |
| MT29F4G08AACWC-ET-C TR  | 557-1363-1-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 12.70 | 11.60 | 10.77 |
| MT29F4G08AACWC-ET-C TR  | 557-1363-2-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 12.70 | 11.60 | 10.77 |
| MT29F4G08ABCHC-C TR     | 557-1364-1-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 11.60 | 10.60 | 9.84  |
| MT29F4G08ABCHC-C TR     | 557-1364-2-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 12.70 | 11.60 | 10.77 |
| MT29F4G08ABCHC-ET-C TR  | 557-1365-1-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 12.70 | 11.60 | 10.77 |
| MT29F4G08ABCHC-ET-C TR  | 557-1365-2-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 12.70 | 11.60 | 10.77 |
| MT29F4G16AACWC-C TR     | 557-1367-1-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 12.14 | 11.09 | 10.30 |
| MT29F4G16AACWC-C TR     | 557-1367-2-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 12.14 | 11.09 | 10.30 |
| MT29F4G16AACWC-ET-C TR  | 557-1368-1-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 13.09 | 11.96 | 11.11 |
| MT29F4G16AACWC-ET-C TR  | 557-1368-2-ND | 4Gb, 3.3V  | 4Gb, 3.3V  | 48-TSOP           | 13.09 | 11.96 | 11.11 |
| MT29F4G16ABCHC-C TR     | 557-1369-1-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 12.14 | 11.09 | 10.30 |
| MT29F4G16ABCHC-C TR     | 557-1369-2-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 12.14 | 11.09 | 10.30 |
| MT29F4G16ABCHC-ET-C TR  | 557-1370-1-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 13.09 | 11.96 | 11.11 |
| MT29F4G16ABCHC-ET-C TR  | 557-1370-2-ND | 4Gb, 1.8V  | 4Gb, 1.8V  | 63-VFBGA          | 13.09 | 11.96 | 11.11 |
| MT29F8G08AAAWP-A TR     | 557-1371-1-ND | 8Gb, 3.3V  | 8Gb, 3.3V  | 48-TSOP           | 16.86 | 15.40 | 14.30 |
| MT29F8G08AAAWP-A TR     | 557-1371-2-ND | 8Gb, 3.3V  | 8Gb, 3.3V  | 48-TSOP           | 16.86 | 15.40 | 14.30 |
| MT29F8G08AAAWP-ET-A TR  | 557-1372-1-ND | 8Gb, 3.3V  | 8Gb, 3.3V  | 48-TSOP           | 16.42 | 15.00 | 13.93 |
| MT29F8G08AAAWP-ET-A TR  | 557-1372-2-ND | 8Gb, 3.3V  | 8Gb, 3.3V  | 48-TSOP           | 16.42 | 15.00 | 13.93 |
| MT29F16G08DAAWP-ET-A TR | 557-1413-1-ND | 16Gb, 3.3V | 16Gb, 3.3V | 48-TSOP           | 39.26 | 38.28 | 35.34 |
| MT29F16G08DAAWP-ET-A TR | 557-1413-2-ND | 16Gb, 3.3V | 16Gb, 3.3V | 48-TSOP           | 39.26 | 38.28 | 35.34 |

| Micron DigiKey®          |               |                             |                                     | PSRAM - 符合 RoHS 规范要求 |       |       |       |
|--------------------------|---------------|-----------------------------|-------------------------------------|----------------------|-------|-------|-------|
| Micron Technology 零件编号   | Digi-Key 零件编号 | 描述                          |                                     | 封装                   | 单价★   |       |       |
| MT45W1MW16BABB-706 WT TR | 557-1006-1-ND | 异步/寻呼/突发 CellularRAM, 16Mb  | Async/Page/Burst CellularRAM, 16Mb  | 54-VFBGA             | 6.22  | 5.60  | 5.08  |
| MT45W1MW16BABB-706 WT TR | 557-1006-2-ND | 异步/寻呼/突发 CellularRAM, 16Mb  | Async/Page/Burst CellularRAM, 16Mb  | 54-VFBGA             | 6.22  | 5.60  | 5.08  |
| MT45W1MW16BDGB-708 AT TR | 557-1419-1-ND | 异步/寻呼/突发 CellularRAM, 16Mb  | Async/Page/Burst CellularRAM, 16Mb  | 54-VFBGA             | 8.60  | 7.79  | 7.14  |
| MT45W1MW16BDGB-708 AT TR | 557-1419-2-ND | 异步/寻呼/突发 CellularRAM, 16Mb  | Async/Page/Burst CellularRAM, 16Mb  | 54-VFBGA             | 8.60  | 7.79  | 7.14  |
| MT45W2MW16BGB-701 IT TR  | 557-1442-1-ND | 异步/寻呼/突发 CellularRAM, 32Mb  | Async/Page/Burst CellularRAM, 32Mb  | 54-VFBGA             | 10.75 | 9.74  | 8.93  |
| MT45W2MW16BGB-701 IT TR  | 557-1442-2-ND | 异步/寻呼/突发 CellularRAM, 32Mb  | Async/Page/Burst CellularRAM, 32Mb  | 54-VFBGA             | 10.75 | 9.74  | 8.93  |
| MT45W2MW16PGA-70 IT TR   | 557-1317-1-ND | 异步/寻呼 CellularRAM, 32Mb     | Async/Page CellularRAM, 32Mb        | 48-VFBGA             | 9.59  | 8.69  | 7.97  |
| MT45W2MW16PGA-70 IT TR   | 557-1317-2-ND | 异步/寻呼 CellularRAM, 32Mb     | Async/Page CellularRAM, 32Mb        | 48-VFBGA             | 9.59  | 8.69  | 7.97  |
| MT45W4MW16PCGA-70 IT TR  | 557-1443-1-ND | 异步/寻呼 CellularRAM, 64Mb     | Async/Page CellularRAM, 64Mb        | 48-VFBGA             | 13.09 | 11.96 | 11.11 |
| MT45W4MW16PCGA-70 IT TR  | 557-1443-2-ND | 异步/寻呼 CellularRAM, 64Mb     | Async/Page CellularRAM, 64Mb        | 48-VFBGA             | 13.09 | 11.96 | 11.11 |
| MT45W8MW16BGX-70 IT TR   | 557-1444-1-ND | 异步/寻呼/突发 CellularRAM, 128Mb | Async/Page/Burst CellularRAM, 128Mb | 54-VFBGA             | 13.40 | 12.23 | 11.36 |
| MT45W8MW16BGX-70 IT TR   | 557-1444-2-ND | 异步/寻呼/突发 CellularRAM, 128Mb | Async/Page/Burst CellularRAM, 128Mb | 54-VFBGA             | 13.40 | 12.23 | 11.36 |

| Qimonda            |               |                  |                  | SDRAM - 符合 RoHS 规范要求 • 由于市场波动, 请参阅 Digi-Key 网站获取最新价格信息。 |          |       |   |
|--------------------|---------------|------------------|------------------|---------------------------------------------------------|----------|-------|---|
| Qimonda 零件编号       | Digi-Key 零件编号 | 描述               |                  | 封装                                                      | 单价★      |       |   |
| HYB39S128160FE-7   | 675-1002-1-ND | 128Mb SDRAM      | 128Mb SDRAM      | 54-TSOP                                                 | 2.68     | —     | — |
| HYB39S128800FE-7   | 675-1001-1-ND | 128Mb SDRAM      | 128Mb SDRAM      | 54-TSOP                                                 | 2.68     | —     | — |
| HYB39S256800FE-7   | 675-1010-1-ND | 256Mb SDRAM      | 256Mb SDRAM      | 54-TSOP                                                 | 2.40     | —     | — |
| HY139S128160FE-7   | 675-1019-1-ND | 128Mb SDRAM      | 128Mb SDRAM      | 54-TSOP                                                 | 2.68     | —     | — |
| HY139S128800FE-7   | 675-1020-1-ND | 128Mb SDRAM      | 128Mb SDRAM      | 54-TSOP                                                 | 2.68     | —     | — |
| HY139S128800FE-7   | 675-1020-2-ND | 128Mb SDRAM      | 128Mb SDRAM      | 54-TSOP                                                 | 4020.00  | 1,500 | — |
| DDR                |               |                  |                  |                                                         |          |       |   |
| HYB25D128800CE-6   | 675-1005-1-ND | 128Mb DDR SDRAM  | 128Mb DDR SDRAM  | 66-TSOP                                                 | 3.13     | —     | — |
| HYB25D128800CE-6   | 675-1005-2-ND | 128Mb DDR SDRAM  | 128Mb DDR SDRAM  | 66-TSOP                                                 | 4230.00  | 1,500 | — |
| HYB25D512160CE-5   | 675-1010-1-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 5.95     | —     | — |
| HYB25D512160CE-5   | 675-1010-2-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 8925.00  | 1,500 | — |
| HYB25D512800CE-5   | 675-1009-1-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 11.64    | —     | — |
| HYB25D512800CE-5   | 675-1009-2-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 10980.00 | 1,500 | — |
| HYB25D512800CE-6   | 675-1008-1-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 5.95     | —     | — |
| HYB25D512800CE-6   | 675-1008-2-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 8925.00  | 1,500 | — |
| HY125D512160CE-5   | 675-1022-1-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 6.00     | —     | — |
| HY125D512160CE-5   | 675-1022-2-ND | 512Mb DDR SDRAM  | 512Mb DDR SDRAM  | 66-TSOP                                                 | 8999.97  | 1,500 | — |
| DDR2               |               |                  |                  |                                                         |          |       |   |
| HYB18T1G160BF-5    | 675-1018-1-ND | 1Gb DDR2 SDRAM   | 1Gb DDR2 SDRAM   | 84-TFBGA                                                | 10.20    | —     | — |
| HYB18T1G800BF-3S   | 675-1017-1-ND | 1Gb DDR2 SDRAM   | 1Gb DDR2 SDRAM   | 68-TFBGA                                                | 8.28     | —     | — |
| HYB18T1G800BF-3S   | 675-1017-2-ND | 1Gb DDR2 SDRAM   | 1Gb DDR2 SDRAM   | 68-TFBGA                                                | 16560.00 | 2,000 | — |
| HYB18T512800BF-2.5 | 675-1013-1-ND | 512Mb DDR2 SDRAM | 512Mb DDR2 SDRAM | 60-TFBGA                                                | 6.41     | —     | — |
| HYB18T512800BF-2.5 | 675-1013-2-ND | 512Mb DDR2 SDRAM | 512Mb DDR2 SDRAM | 60-TFBGA                                                | 12820.00 | 2,000 | — |
| HYB18T512800BF-3.7 | 675-1011-1-ND | 512Mb DDR2 SDRAM | 512Mb DDR2 SDRAM | 60-TFBGA                                                | 3.00     | —     | — |
| HYB18T512800BF-3S  | 675-1012-1-ND | 512Mb DDR2 SDRAM | 512Mb DDR2 SDRAM | 60-TFBGA                                                | 6.41     | —     | — |
| HYB18T512800BF-3S  | 675-1012-2-ND | 512Mb DDR2 SDRAM | 512Mb DDR2 SDRAM | 60-TFBGA                                                | 12820.00 | 2,000 | — |

| DigiKey®            |                            |                                           |         | 存储器    |      |       |  |
|---------------------|----------------------------|-------------------------------------------|---------|--------|------|-------|--|
| 提供符合 RoHS 规范要求的零件   |                            |                                           |         | 单价★    |      |       |  |
| Digi-Key 零件编号       | 描述                         |                                           | 封装      | 1      | 10   | 25    |  |
| SRAM                |                            |                                           |         |        |      |       |  |
| 微芯片技术               |                            |                                           |         |        |      |       |  |
| 23A640-I/P-ND       | 64K (8Kx8) 串行 SRAM, 1.7V   | 64K (8Kx8) Serial SRAM 1.7V               | 8-PDIP  | .90    | .64  | .62   |  |
| 23A640-I/SN-ND      | 64K (8Kx8) 串行 SRAM, 1.7V   | 64K (8Kx8) Serial SRAM 1.7V               | 8-SOIC  | .86    | .62  | .60   |  |
| 23A640-I/ST-ND      | 64K (8Kx8) 串行 SRAM, 1.7V   | 64K (8Kx8) Serial SRAM 1.7V               | 8-TSSOP | .92    | .66  | .64   |  |
| 23K640-I/P-ND       | 64K (8Kx8) 串行 SRAM, 2.7V   | 64K (8Kx8) Serial SRAM 2.7V               | 8-PDIP  | .90    | .64  | .62   |  |
| 23K640-I/SN-ND      | 64K (8Kx8) 串行 SRAM, 2.7V   | 64K (8Kx8) Serial SRAM 2.7V               | 8-SOIC  | .86    | .62  | .60   |  |
| 23K640-I/ST-ND      | 64K (8Kx8) 串行 SRAM, 2.7V   | 64K (8Kx8) Serial SRAM 2.7V               | 8-TSSOP | .92    | .66  | .64   |  |
| 23A256-I/P-ND       | 256K (32Kx8) 串行 SRAM, 1.7V | 256K (32Kx8) Serial SRAM 1.7V             | 8-PDIP  | 1.66   | 1.18 | 1.14  |  |
| 23A256-I/SN-ND      | 256K (32Kx8) 串行 SRAM, 1.7V | 256K (32Kx8) Serial SRAM 1.7V             | 8-SOIC  | 1.62   | 1.16 | 1.12  |  |
| 23A256-I/ST-ND      | 256K (32Kx8) 串行 SRAM, 1.7V | 256K (32Kx8) Serial SRAM 1.7V             | 8-TSSOP | 1.68   | 1.20 | 1.16  |  |
| 23K256-I/P-ND       | 256K (32Kx8) 串行 SRAM, 2.7V | 256K (32Kx8) Serial SRAM 2.7V             | 8-PDIP  | 1.66   | 1.18 | 1.14  |  |
| 23K256-I/SN-ND      | 256K (32Kx8) 串行 SRAM, 2.7V | 256K (32Kx8) Serial SRAM 2.7V             | 8-SOIC  | 1.62   | 1.16 | 1.12  |  |
| 23K256-I/ST-ND      | 256K (32Kx8) 串行 SRAM, 2.7V | 256K (32Kx8) Serial SRAM 2.7V             | 8-TSSOP | 1.68   | 1.20 | 1.16  |  |
| Toshiba             |                            |                                           |         |        |      |       |  |
| TC55VEM416AXGN55-ND | 16M 位 SRAM (1M x 16)       | 16M-Bit SRAM (1M x 16)                    | 48-BGA  | 18.13  | —    | 15.42 |  |
| 串行 EEPROM           |                            |                                           |         |        |      |       |  |
| 微芯片技术               |                            |                                           |         |        |      |       |  |
| AC812001-ND         | PICSEETM 介绍设计套件            | PICSEETM Introduction Design Kit          | —       | 330.00 | —    | —     |  |
| SEEPROM1-KIT-ND     | Digi-Key® 低密度串行 EEPROM 套件  | Digi-Key® Low-Density Serial EEPROM Kit   | —       | 17.95  | —    | —     |  |
| SEEPROM2-KIT-ND     | Digi-Key® 中密度串行 EEPROM 套件  | Digi-Key® Mid-Density Serial EEPROM Kit   | —       | 17.95  | —    | —     |  |
| SEEPROM3-KIT-ND     | Digi-Key® 高密度串行 EEPROM 套件  | Digi-Key® High-Density Serial EEPROM Kit  | —       | 19.95  | —    | —     |  |
| SEEPROM4-KIT-ND     | Digi-Key® 组合密度串行 EEPROM 套件 | Digi-Key® Combo-Density Serial EEPROM Kit | —       | 29.95  | —    | —     |  |

\* 符合 RoHS 规范要求

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